

DATA SHEET



BC556; BC557 PNP general purpose transistors

Product data sheet
Supersedes data of 1999 Apr 15

2004 Oct 11

PNP general purpose transistors

BC556; BC557

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

APPLICATIONS

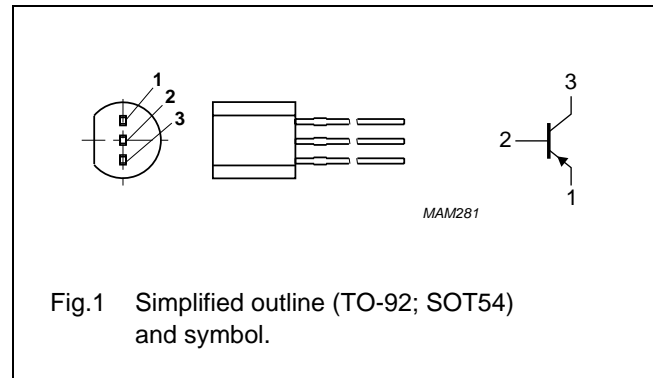
- General purpose switching and amplification.

DESCRIPTION

PNP transistor in a TO-92; SOT54 plastic package.
NPN complements: BC546 and BC547.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | emitter |
| 2 | base |
| 3 | collector |



ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|---|---------|
| | NAME | DESCRIPTION | VERSION |
| BC556 | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |
| BC557 | | | |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|---------------------------|-----------------------------|------|------|------|
| V_{CBO} | collector-base voltage | open emitter | | | |
| | BC556 | | – | –80 | V |
| | BC557 | | – | –50 | V |
| V_{CEO} | collector-emitter voltage | open base | | | |
| | BC556 | | – | –65 | V |
| | BC557 | | – | –45 | V |
| V_{EBO} | emitter-base voltage | open collector | – | –5 | V |
| I_C | collector current (DC) | | – | –100 | mA |
| I_{CM} | peak collector current | | – | –200 | mA |
| I_{BM} | peak base current | | – | –200 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25\text{ °C}$ | – | 500 | mW |
| T_{stg} | storage temperature | | –65 | +150 | °C |
| T_j | junction temperature | | – | 150 | °C |
| T_{amb} | ambient temperature | | –65 | +150 | °C |

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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | note 1 | 250 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

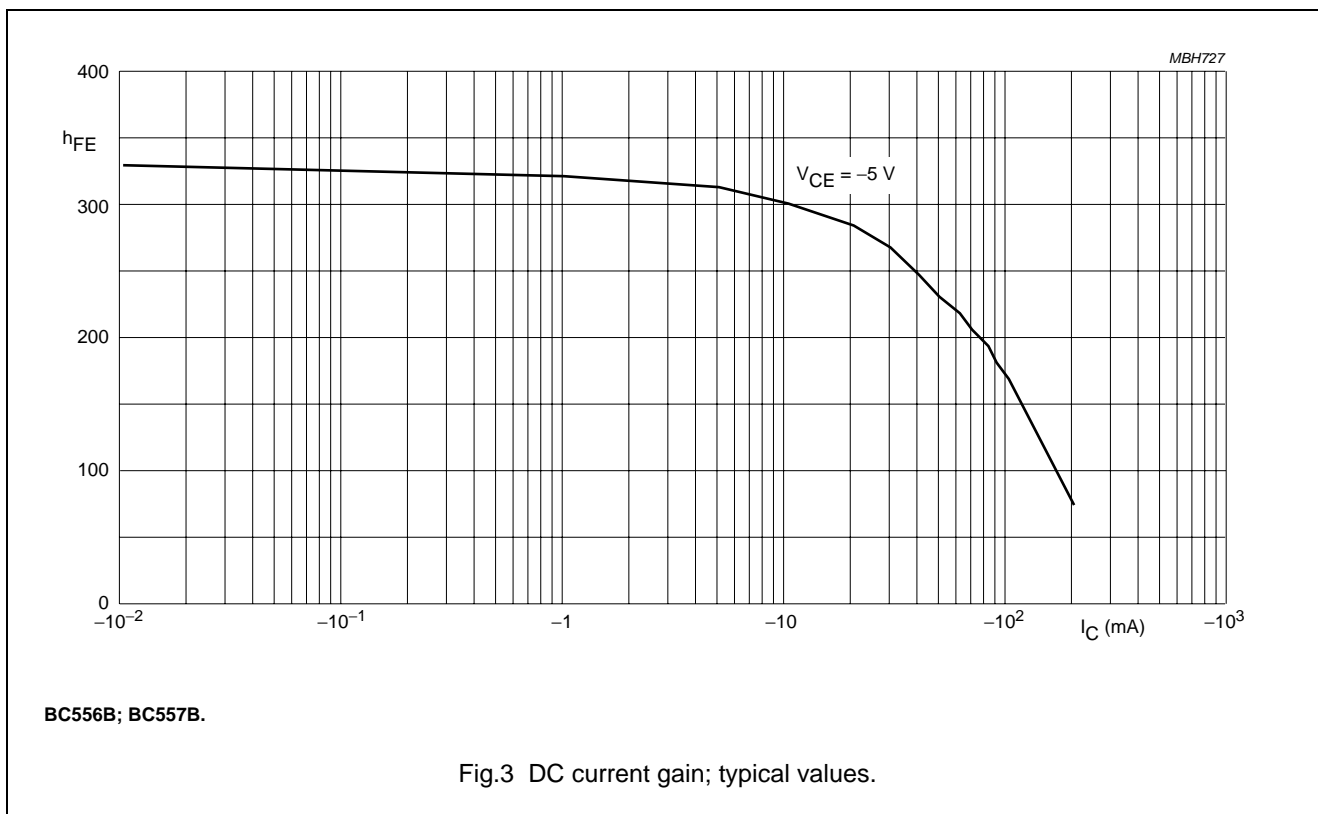
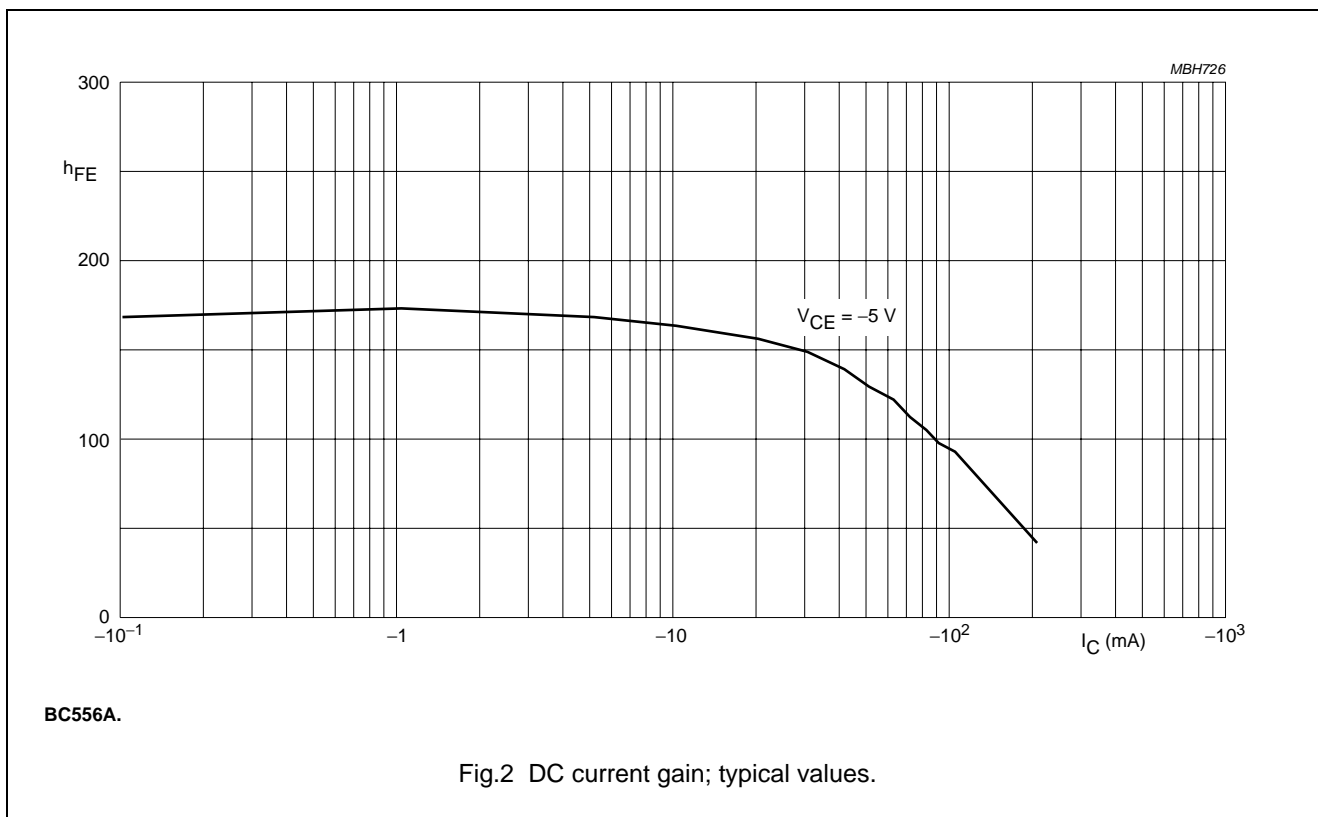
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------|---|---|------|------|------|---------------|
| I_{CBO} | collector-base cut-off current | $V_{CB} = -30\text{ V}; I_E = 0\text{ A}$ | – | –1 | –15 | nA |
| | | $V_{CB} = -30\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ °C}$ | – | – | –4 | μA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = -5\text{ V}; I_C = 0\text{ V}$ | – | – | –100 | nA |
| h_{FE} | DC current gain BC556 BC557 BC556A BC556B; BC557B BC557C | $I_C = -2\text{ mA}; V_{CE} = -5\text{ V};$ see Figs 2, 3 and 4 | 125 | – | 475 | |
| | | | 125 | – | 800 | |
| | | | 125 | – | 250 | |
| | | | 220 | – | 475 | |
| | | | 420 | – | 800 | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$ | – | –60 | –300 | mV |
| | | $I_C = -100\text{ mA}; I_B = -5\text{ mA}$ | – | –180 | –650 | mV |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA};$ note 1 | – | –750 | – | mV |
| | | $I_C = -100\text{ mA}; I_B = -5\text{ mA};$ note 1 | – | –930 | – | mV |
| V_{BE} | base-emitter voltage | $V_{CE} = -5\text{ V}; I_C = -2\text{ mA};$ note 2 | –600 | –650 | –750 | mV |
| | | $V_{CE} = -5\text{ V}; I_C = -10\text{ mA};$ note 2 | – | – | –820 | mV |
| C_c | collector capacitance | $V_{CB} = -10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$ | – | 3 | – | pF |
| C_e | emitter capacitance | $V_{EB} = -0.5\text{ V}; I_C = i_c = 0\text{ A}; f = 1\text{ MHz}$ | – | 10 | – | pF |
| f_T | transition frequency | $V_{CE} = -5\text{ V}; I_C = -10\text{ mA}; f = 100\text{ MHz}$ | 100 | – | – | MHz |
| F | noise figure | $V_{CE} = -5\text{ V}; I_C = -200\text{ }\mu\text{A}; R_S = 2\text{ k}\Omega;$ $f = 1\text{ kHz}; B = 200\text{ Hz}$ | – | 2 | 10 | dB |

Notes

1. V_{BEsat} decreases by about -1.7 mV/K with increasing temperature.
2. V_{BE} decreases by about -2 mV/K with increasing temperature.

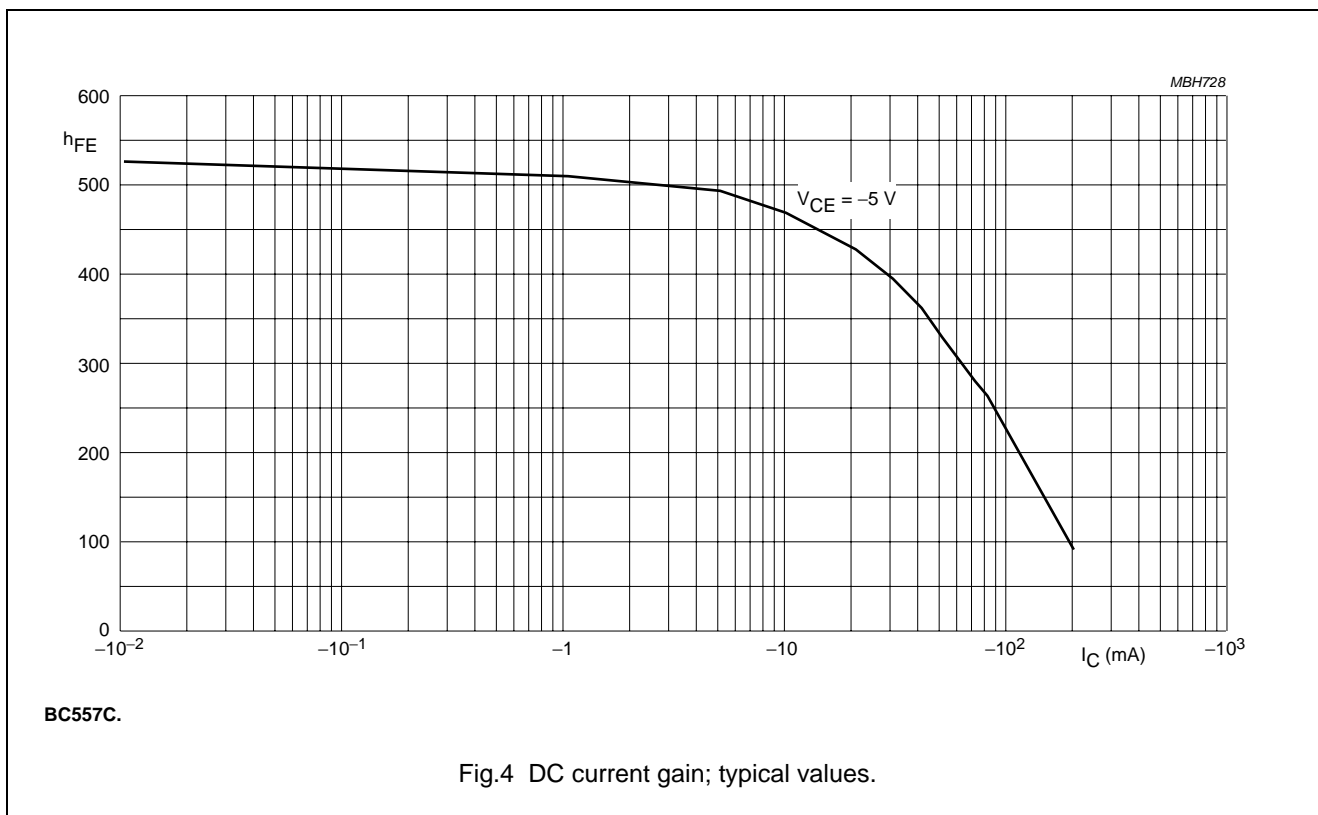
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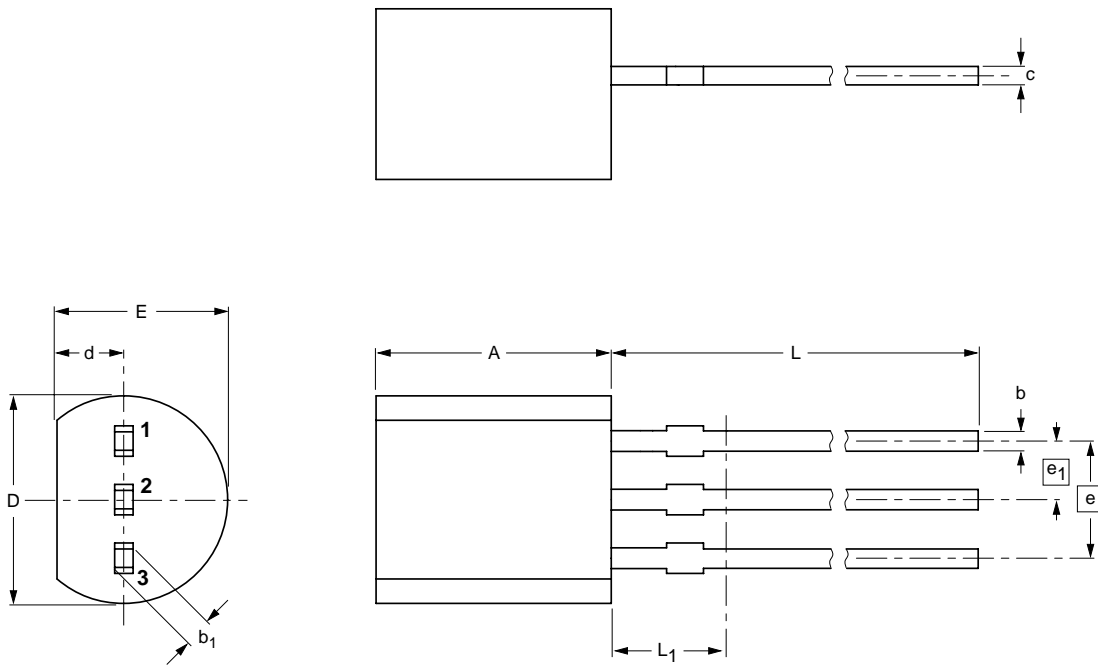
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

| UNIT | A | b | b ₁ | c | D | d | E | e | e ₁ | L | L ₁ ⁽¹⁾ max. |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.55 | 0.45 0.38 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|--------|---------------------|----------------------|
| | IEC | JEDEC | JEITA | | |
| SOT54 | | TO-92 | SC-43A | | 04-06-28 04-11-16 |

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DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|--------------------------------|-------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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